

PART NUMBER 74C941N-ROCV

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

 Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



MM54C941/MM74C941 Octal Buffers/Line Receivers/Line Drivers with TRI-STATE® Outputs

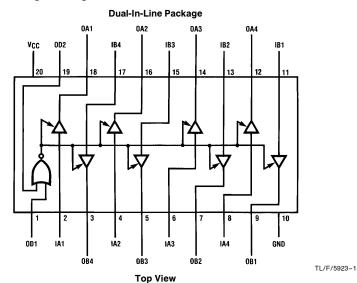
General Description

These octal buffers and line drivers are monolithic complementary MOS (CMOS) integrated circuits with TRI-STATE outputs. These outputs have been specially designed to drive highly capacitive loads such as bus-oriented systems. These devices have a fan-out of 6 low power Schottky loads. When $\rm V_{CC}=5V$, inputs can accept true TTL high and low logic levels.

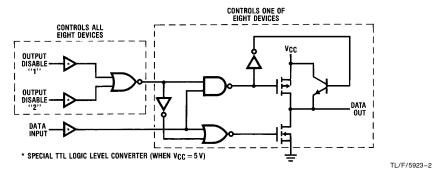
Features

- Wide supply voltage range (3V to 15V)
- Low power consumption
- TTL compatibility (Improved on the inputs)
- High capacitive load
- TRI-STATE outputs
- Input protection
- 20-pin dual-in-line package
- High output drive

Connection and Logic Diagrams



Order Number MM54C941 or MM74C941



Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Voltage at Any Pin

Operating Temperature Range (T_A) MM54C941

MM74C941

0.3V to $V_{\mbox{\footnotesize CC}}$ + 0.3V -55°C to +125°C -40°C to +85°C Storage Temperature Range (T_S)

Power Dissipation (PD)

Dual-In-Line 700 mW 500 mW Small Outline Operating V_{CC} Range 3V to 15V V_{CC} 18V

 -65°C to $+150^{\circ}\text{C}$

260°C

Lead Temperature (T_I)

(Soldering, 10 seconds)

DC Electrical Characteristics Min/Max limits apply across temperature range, unless otherwise noted

Symbol	Parameter	Conditions	Min	Тур	Max	Units			
CMOS TO CMOS									
V _{IN(1)}	Logical "1" Input Voltage	$V_{CC} = 5.0V$ $V_{CC} = 10V$	2.5 8.0			V V			
V _{IN(0)}	Logical "0" Input Voltage	$V_{CC} = 5.0V$ $V_{CC} = 10V$			0.8 2.0	V V			
V _{OUT(1)}	Logical "1" Output Voltage	$V_{CC} = 5.0V, I_{O} = -10\mu A$ $V_{CC} = 10V, I_{O} = -10\mu A$	4.5 9.0			V			
V _{OUT(0)}	Logical "0" Output Voltage	$V_{CC} = 5.0V$, $I_{O} = 10 \mu A$ $V_{CC} = 10V$, $I_{O} = 10 \mu A$			0.5 1.0	V V			
I _{IN(1)}	Logical "1" Input Current	$V_{CC} = 15V, V_{IN} = 15V$		0.005	1.0	μΑ			
I _{IN(0)}	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1.0	-0.005		μΑ			
Icc	Supply Current	$V_{CC} = 15V$		0.05	300	μΑ			
loz	TRI-STATE Leakage	$V_{CC} = 15V$, $V_{OUT} = 0V$ or 15V			±10	μΑ			
CMOS/TTL INTERFACE									
V _{IN(1)}	Logical "1" Input Voltage	54C, V _{CC} = 4.5V 74C, V _{CC} = 4.75V	V _{CC} -2.5 V _{CC} -2.5			V V			
V _{IN(0)}	Logical "0" Input Voltage	54C, V _{CC} = 4.5V 74C, V _{CC} = 4.75V			0.8 0.8	V			
V _{OUT(1)}	Logical "1" Output Voltage	54C, $V_{CC} = 4.5V$, $I_{O} = -450 \mu A$ 74C, $V_{CC} = 4.75V$, $I_{O} = -450 \mu A$ 54C, $V_{CC} = 4.5V$, $I_{O} = -2.2 mA$ 74C, $V_{CC} = 4.75V$, $I_{O} = -2.2 mA$	V _{CC} -0.4 V _{CC} -0.4 2.4 2.4			V V V			
V _{OUT(0)}	Logical "0" Output Voltage	54C, $V_{CC} = 4.5V$, $I_{O} = 2.2 \text{ mA}$ 74C, $V_{CC} = 4.75V$, $I_{O} = 2.2 \text{ mA}$			0.4 0.4	V			
OUTPUT DRIVE (See 54C/74C Family Characteristics Data Sheet)									
ISOURCE	Output Source Current (P-Channel)	$V_{CC} = 5.0V, V_{OUT} = 0V$ $T_A = 25^{\circ}C$	-14.0	-30.0		mA			
ISOURCE	Output Source Current (P-Channel)	$V_{CC} = 10V, V_{OUT} = 0V$ $T_A = 25^{\circ}C$	-36.0	-70.0		mA			
Isink	Output Sink Current (N-Channel)	$V_{CC} = 5.0V, V_{OUT} = V_{CC}$ $T_A = 25^{\circ}C$	12.0	20.0		mA			
I _{SINK}	Output Sink Current (N-Channel)	$V_{CC} = 10V$, $V_{OUT} = V_{CC}$ $T_A = 25$ °C	48.0	70		mA			

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

AC Electrical Characteristics* T _A = 25°C, C _L = 50 pF, unless otherwise specified								
Symbol	Parameter	Conditions	Min	Тур	Max	Units		
^t pd1, ^t pd0	Propagation Delay (Data IN to OUT)	$\begin{aligned} &V_{CC} = 5.0 \text{V}, C_L = 50 \text{pF} \\ &V_{CC} = 10 \text{V}, C_L = 50 \text{pF} \\ &V_{CC} = 5.0 \text{V}, C_L = 150 \text{pF} \\ &V_{CC} = 10 \text{V}, C_L = 150 \text{pF} \end{aligned}$		70 35 90 45	140 70 160 90	ns ns ns		
t _{IH} , t _{OH}	Propagation Delay Output Disable to Logic Level (from High Impedance State) (from a Logic Level)	$\begin{aligned} R_L &= 1 \text{ k}\Omega, C_L = 50 \text{ pF} \\ V_{CC} &= 5.0 \text{V} \\ V_{CC} &= 210 \text{V} \end{aligned}$		100 55	200 110	ns ns		
t _{H1,} t _{H0}	Propagation Delay Output Disable to Logic Level (from High Impedance State)	$\begin{aligned} R_L &= 1 \text{ k}\Omega, C_L = 50 \text{ pF} \\ V_{CC} &= 5.0 \text{V} \\ V_{CC} &= 10 \text{V} \end{aligned}$		100 55	200 110	ns ns		
t _{THL,} t _{TLH}	Transition Time	$\begin{aligned} &V_{CC} = 5.0 \text{V}, C_L = 50 \text{ pF} \\ &V_{CC} = 10 \text{V}, C_L = 50 \text{ pF} \\ &V_{CC} = 5.0 \text{V}, C_L = 150 \text{ pF} \\ &V_{CC} = 10 \text{V}, C_L = 150 \text{ pF} \end{aligned}$		50 30 80 50	100 60 160 100	ns ns ns		
C _{PD}	Power Dissipation Capacitance (Output Enabled per Buffer) (Output Disabled per Buffer)	(Note 3)		100 10		pF pF		
C _{IN}	Input Capacitance (Any Input)	(Note 2) $V_{\text{IN}} = 0 \text{V, f} = 1 \text{ MHz,}$ $T_{\text{A}} = 25^{\circ}\text{C}$		10		pF		
CO	(Output Capacitance) (Output Disabled)	$V_{IN} = 0V$, $f = 1$ MHz, $T_A = 25$ °C		10		pF		

^{*}AC Parameters are guaranteed by DC correlated testing.

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Capacitance is guaranteed by periodic testing.

Note 3: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics Application Note, AN-90.

Truth Table

OD1	OD2	Input	Output
0	0	0	0
0	0	1	1
0	1	Х	Z
1	0	Х	Z
1	1	Х	Z

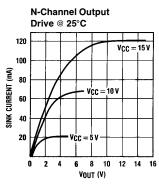
^{1 =} High

^{0 =} Low

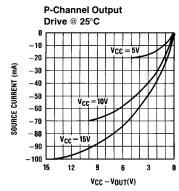
X = Don't Care

Z = TRI-STATE

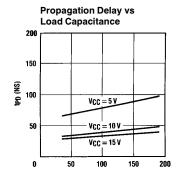
Typical Performance Characteristics



TL/F/5923-3

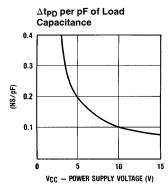


TL/F/5923-4



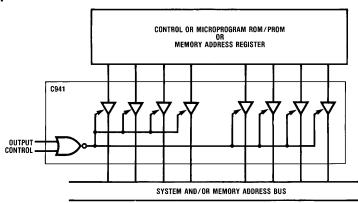
CL (pF)

TL/F/5923-5



TL/F/5923-6

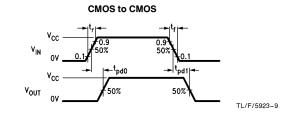
Typical Application

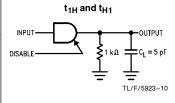


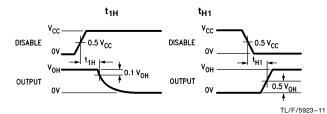
TL/F/5923-7

AC Test Circuits and Switching Time Waveforms

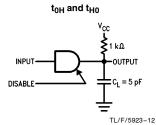
$v_{\text{IN}} \circ \underbrace{ \begin{array}{c} t_{\text{pd0}}, t_{\text{pd1}} \\ \\ \hline \\ \end{array}}_{\text{CL}} \circ v_{\text{OUT}}$



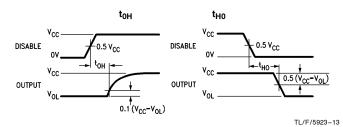




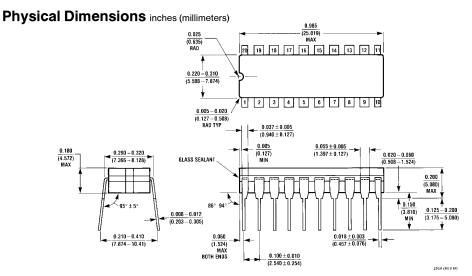
Note: v_{OH} is defined as the DC output high voltage when the device is loaded with a 1 k Ω resistor to ground.



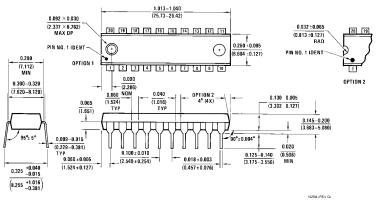
Note: Delays measured with input $t_{f_{i}}\,t_{f}\leq$ 20 ns.



Note: V_{OL} is defined as the DC output low voltage when the device is loaded with a 1 $k\Omega$ resistor to V_{CC}



Ceramic Dual-In-Line Package (J) Order Number MM54C941J or MM74C941J NS Package Number J20A



Molded Dual-In-Line Package (N) Order Number MM54C941N or MM74C941N NS Package Number N20A

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National Semiconductor

National Semiconducto Corporation 1111 West Bardin Road Arlington, TX 76017 Tel: 1(800) 272-9959 Fax: 1(800) 737-7018

National Semiconductor Europe

Fax: (+49) 0-180-530 85 86 Fax: (+49) U-18U-35U oo oo Email: onjwege etevm2.nsc.com Deutsch Tel: (+49) 0-180-530 85 85 English Tei: (+49) 0-180-532 78 32 Français Tel: (+49) 0-180-532 93 58 Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.

Tsimshatsui, Kowloon Hong Kong Tel: (852) 2737-1600 Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
Tel: 81-043-299-2309
Fax: 81-043-299-2408